ATLAS IBL operational experience

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The Insertable B-Layer (IBL) is the inner most pixel layer in the ATLAS experiment, which was installed at a 3.3 cm radius from the beam axis in 2014 to improve the tracking performance. To cope with the high radiation and hit occupancy due to proximity to the interaction point, a new read-out chip and two different silicon sensor technologies (planar and 3D) have been developed for the IBL. After the long shut-down period over 2013 and 2014, the ATLAS experiment started data-taking in May 2015 for Run-2 of the Large Hadron Collider (LHC). The IBL has been operated successfully since the beginning of Run-2 and shows excellent performance with a low dead module fraction, high data-taking efficiency and improved tracking capability. The experience and challenges in operation of the IBL are described and results on the performance are presented.
1. Introduction

The Pixel Detector used in Run-1 is designed to work at the instantaneous luminosity of $1 \times 10^{34}$ cm$^{-2}$s$^{-1}$. The instantaneous luminosity of the Large Hadron Collider (LHC) is expected to increase up to $3 \times 10^{34}$ cm$^{-2}$s$^{-1}$ after long shutdown 2 (LS2) which is planned in 2019. As the luminosity increases the hit data rate becomes a serious issue for the front-end electronics. To cope with the increase during Run-2, a new pixel sensor layer, IBL \cite{1}, was installed as the inner most layer in 2014. This was the first upgrade project in the ATLAS detector \cite{2}.

The installation of the IBL was strongly motivated by physics analysis as well. For example, $b$-jet tagging is used in about 65% of the analysis results published by the ATLAS collaboration at the ICHEP conference in 2016 \cite{3}. Providing additional hit information at the closest position to the beam collision point, the IBL significantly improves the performance of $b$-jet tagging.

After the long shut-down period over 2013 and 2014 (LS1), the ATLAS experiment started data-taking in May 2015 for Run-2 of the LHC. The IBL has been successfully operated and shows excellent performance. In the following sections, the experience and challenges in the operation of the IBL are described as well as its performance.

2. Insertable B-Layer (IBL)

In the IBL, two different sensor technologies are adopted: $n^+$-in-n planar sensors \cite{4} and 3D sensors \cite{5}. The pixel size of the sensors is $50 \times 250$ μm$^2$ which is 60% of the pixel size used for the Pixel Detector ($50 \times 400$ μm$^2$). The IBL has about 12 million pixels in total. The thickness of the planar and 3D sensors is 200 μm and 230 μm, respectively. In the planar sensor, the slim-edge of 200 μm with long pixels under the guard-ring is adopted to minimize inactive region. The sensors were designed to work at a fluence of up to $5 \times 10^{15}$ 1 MeV n$_{eq}$, which is the expected fluence by the end of LHC Phase-1 operation around 2022.

A new front-end chip (FE-I4B) was developed for the IBL. The FE-I4B is produced with IBM 130 nm technology, and 80 $\times$ 336 pixels are embedded per chip. It is designed to be radiation hard up to a 250 Mrad ionizing dose. The signals from the sensor are amplified and digitized in analog and digital circuits respectively, and finally the charge information is output with 4-bit value of the time over threshold (TOT).
Figure 2: Hit occupancy at each pixel layer as a function of the number of pile-up events ($\mu$). IBL, B-Layer, Layer-1 and Layer-2 are placed at the radius of 33, 50.5, 88.5 and 122.5 mm, respectively, centered around the beam axis [6].

An IBL module consists of a sensor bump-bonded to an FE-I4B chip with flex cables which provide electric lines. The modules are mounted on the staves where planar sensors are used for 75% of the middle region in $\eta$ and 3D sensors used in the remaining 25% (high $\eta$). The full IBL consists of 14 staves integrated into a support tube. The IBL surrounds a new beam pipe, and is contained in a package of 7 m long in the limited radial envelope of 10 mm. The IBL was transported to the ATLAS experimental hall 90 m underground on May 5, 2014 and installed into the ATLAS detector on May 7 as shown in Fig. [1]. To install the IBL in the limited space inside B-Layer, an insertion clearance of less than 0.1 mm was available.

3. Performance of IBL in ATLAS Run-2 operation

The ATLAS experiment started data-taking in May 2015 for Run-2 of the LHC. The IBL has been operating successfully since the beginning of Run-2 and shows excellent performance with low dead module fraction, high data-taking efficiency and improved tracking capability as summarized in this section.

3.1 Detector stability in data-taking

One of the big achievements in the IBL operation is that 100% of the sensors and FE-I4B chips are kept operational in the tracking coverage region of $|\eta| < 2.5$ during Run-2. It allows the IBL to show full tracking performance.

Figure [2][6] shows the hit occupancy at each pixel layer as a function of the number of pile-up events ($\mu$). The hit occupancy at the IBL increases linearly with $\mu$, and has been successful even at high $\mu$. Actually, the rate of desynchronization in the readout is of the order of 0.1% at the IBL and this value is about one order of magnitude less than those of the other Pixel layers.
3.2 Position resolution and hit efficiency

Figure 3 shows the hit position resolution on the IBL in the $r$-$\phi$ (left) and $z$ (middle) projections as a function of cluster width along $\phi$ and the track $|\eta|$, respectively, and efficiency of associating an IBL hit to a reconstructed particle track as a function of the particle $p_T$ (right). The selected $Z \rightarrow \mu\mu$ events in collision data (circles with error bars) and simulation (lines) are used for these plots.

Figure 4: $d_0$ (left) and $z_0$ resolution (right) as a function of $p_T$ in ATLAS Run-1 (without IBL) and Run-2 (with IBL).

The IBL provides the hit information at the closest position to the beam collision point, and it improves the impact parameter resolution. Figure 4 shows $d_0$ and $z_0$ resolution in Run-1.
Figure 5: The light jet rejection versus $b$-jet tagging efficiency for the MV1c $b$-tagging algorithm using the Run-1 detector and reconstruction software (blue) compared to the MV2c20 $b$-tagging algorithm using the Run-2 setup (red) [9].

and Run-2. The impact parameter resolutions are better in Run-2 with the IBL. At low transverse momentum ($p_T$) region, and it is improved by about 40% at $p_T$ below 1 GeV for both $d0$ and $z0$.

3.3 $b$-jet tagging performance

The better impact parameter resolution with the IBL improves performance of $b$-jet tagging. Figure 5 shows simulation results for two software algorithms: MV1c and MV2c20. The light jet rejection as a function of $b$-jet tagging efficiency for MV1c $b$-tagging algorithm using the Run-1 detector and reconstruction software (blue) compared to the MV2c20 $b$-tagging algorithm using the Run-2 setup [9]. The light jet rejection shows better performance with the IBL together with improvements in the algorithm of $b$-jet tagging.

3.4 $dE/dx$ measurement

$dE/dx$ information is important especially for physics analysis to find new heavy particles predicted in physics beyond the Standard Model [10]. The IBL gives another measurement of charge deposition in the pixel sensors which improves the $dE/dx$ measurement. Figure 6 shows a distribution of $dE/dx$ obtained with (black dots) and without the IBL (red triangles) (left) and bi-dimensional distribution of $dE/dx$ and momentum (right). It can be seen that the distribution of $dE/dx$ in Fig. 6(left) becomes narrower with the IBL. In addition, the particle types are clearly separated in Fig. 6(right), and this information is used for particle identification in physics analyses.

4. Challenges in IBL operation

The IBL has faced several challenges like wire-bond oscillation, distortion of the staves with changing temperature and low-voltage (LV) current increase due to total ionizing dose (TID) effect.
Coping with these challenges, the detector has been successfully operated in stable condition during Run-2 in 2015 and 2016. In this section, the challenges faced in the operation and the treatment for them are described.

4.1 Wire bond oscillation

Wire bonding is used to connect the FE-I4B chip to the flex cables on the IBL module. The digital circuit of the FE-I4B chip consumes current which is susceptible to consecutive triggers or calibration scans \cite{12}. Accordingly, the wire bonds may oscillate at relatively high frequency in the magnetic field of 2 T where the IBL is located. Figure \ref{fig:7} shows the oscillation amplitude as a function of the frequency obtained experimentally for a 2.8 mm wire under IBL-like conditions. Depending on the oscillation amplitude and number of cycles, micro-cracks can develop at the wire bond heal and, even more, the wire can cross the material elastic limit. Both aspects may lead to possible failures on the bond.

To mitigate this effect, the trigger cycle sent to the FE-I4B chip was manipulated to avoid the resonance frequency of the wire bonds. In operation of the IBL, a fixed frequency trigger

Figure 6: Distribution of $dE/dx$ obtained with (black dots) and without the IBL (red triangles) (left) and bi-dimensional distribution of $dE/dx$ and momentum (right) \cite{11}. In the right plot, the distributions of the most probable value for the fitted probability density functions of pions, kaons and protons are superimposed.

Figure 7: Oscillation amplitude expressed in wire diameter (25 μm) as a function of the frequency for a wire of 2.8 mm length obtained under IBL-like conditions \cite{12}.
veto (FFTV) was newly implemented in data-taking system to limit the number of triggers in the resonance region.

4.2 Mechanical distortion of IBL staves

During the commissioning of the IBL, distortion of the staves was found. The magnitude of the distortion depends on the operating temperature as shown in Fig. 8 and it is caused by a mismatch between the coefficients of thermal expansion (CTE) of a bare stave made with the carbon foam and the flex cable attached on the bare stave. The maximum displacement due to the distortion is more than 300 μm at the planned operating temperature of -20 °C with respect to the nominal position at the room temperature.

In the operation of the IBL, the impact of this effect is mitigated by temperature control at the level of 0.2 K and the regular alignment correction in the offline reconstruction.

4.3 Effect of total ionizing dose on FE-I4B

The LV current consumption in FE-I4B chips increased in 2015. This was caused by the effect of TID on NMOS transistors in the chip. Significant leakage current was induced by positive charges trapped in the bulk of the shallow trench isolation (STI) in NMOS transistor.

The increase of the leakage current causes several issues in the detector operation: In the worst case, and if only one power wire bond is left, the IBL module approaches the maximum LV current of 0.55 A. In 2015 the current started to approach this limit before mitigating actions were taken. In addition, it was observed that this phenomenon causes detuning of ToT and threshold values.

The power consumption in a FE-I4B increases with more LV current, and it changes temperature on the module. As described in Sec. 4.2 the different temperature on the modules causes distortion of the staves accordingly.

To study this effect as a function of TID the measurement of LV current in a FE-I4B chip was performed after irradiating it with an x-ray source and proton beam. The results showed...
that LV current increases until about 1 Mrad where it begins to decrease again\cite{16}. This can be explained by the interface traps filling with electrons in front of STI after the positive charge has been trapped there. This layer of negative charge compensates for the effect of trapped holes in the STI. In addition, it was found that the LV current can be decreased by operating the chip at higher temperature due to the annealing effect\cite{16}.

Taking into account the results of these measurements, the operating temperature of the IBL was increased to 15 $^\circ$C at the beginning of 2016 from $-10$ $^\circ$C in 2015 and then eventually decreased again to 5 $^\circ$C. In addition, the digital supply-voltage was decreased to 1.0 V from 1.2 V until the TID was more than 4 Mrad. Figure 9\cite{18} shows the mean LV current of four FE-I4B chips in one LV channel group against integrated luminosity and TID. Although there were significant increases in LV current during 2015, it became stabilized and contained in 2016.

5. Summary and conclusions

The IBL is the inner pixel layer in the ATLAS experiment, which was installed at a 3.3 cm radius from the beam axis in 2014 to improve the tracking performance. After LS1, the ATLAS experiment started data-taking in May 2015 for Run-2 of the LHC. The IBL has been operated successfully since the beginning of Run-2 and shows excellent performance with the low dead module fraction, high data-taking efficiency and improved tracking capability.

The additional hit information provided by the IBL at the closest position to the beam collision point provides invaluable information. It significantly improves the tracking performance, $b$-jet tagging and $dE/dx$ measurements for example.

Operating the IBL has faced several challenges like wire-bond oscillation, distortion of the staves with changing temperature and LV current increase due to TID effect. Coping with these challenges, the detector has been successfully operated in stable conditions during Run-2 in 2015 and 2016.
References


